

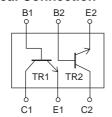
# FH104

# High-Frequency Low-Noise Amplifier, Differential Amplifier Applications

#### **Features**

- Composite type with 2 transistors contained in the MCP package currently in use, improving the mounting efficiency greatly.
- The FH104 is formed with two chips equivalent to the 2SC4853 placed in one package.
- · Excellent in thermal equilibrium and pair capability.

#### **Electrical Connection**



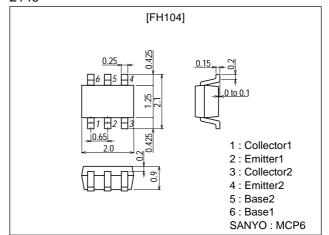
# **Specifications**

#### **Absolute Maximum Ratings** at Ta = 25°C

## **Package Dimensions**

unit:mm

2149



Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		12	V
Collector-to-Emitter Voltage	VCEO		6	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		1.5	V
Collector Current	IC		15	mA
Collector Dissipation	PC	1 unit	80	mW
Total Dissipation	PT		150	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### **Electrical Characteristics** at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
r arameter				typ	max	Unit
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0			1.0	μΑ
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =1V, I <sub>C</sub> =0			10	μA
DC Current Gain	hFE	V <sub>CE</sub> =1V, I <sub>C</sub> =1mA	90		200	
DC Current Gain Ratio	hFE (small/large)	V <sub>CE</sub> =1V, I <sub>C</sub> =1mA	0.7	0.95		
Base-to-Emitter Voltage Difference	V <sub>BE</sub> (large-small)	V <sub>CB</sub> =1V, I <sub>C</sub> =1mA		1.0		mV

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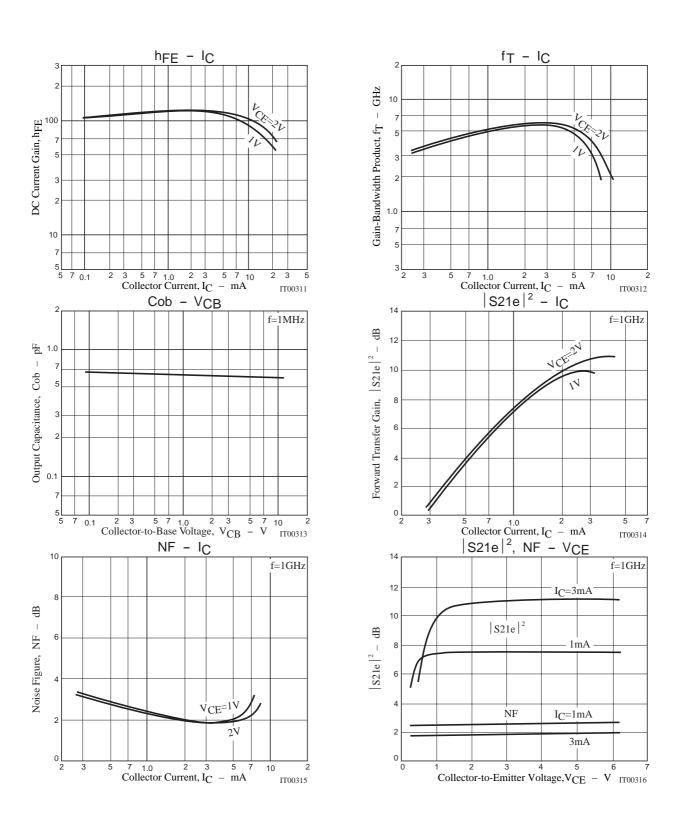
Note) The specifications shown above are for each individual transistor. However, the ratings for  $h_{FE}$  (small/large) and  $V_{BE}$  (large-small) indicate pair characteristics.

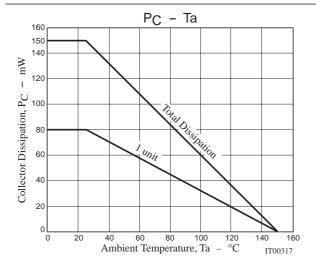
Marking: 104

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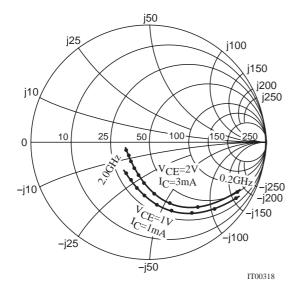
Parameter	Symbol	Conditions		Ratings		
Falametei	Symbol			typ	max	Unit
Gain-Bandwidth Product		V <sub>CE</sub> =1V, I <sub>C</sub> =1mA		5		GHz
Output Capacitance	Cob	V <sub>CB</sub> =1V, f=1MHz		0.6	1.0	pF
Forward Transfer Gain	S21e   <sup>2</sup> 1	V <sub>CE</sub> =1V, I <sub>C</sub> =1mA, f=1GHz	4.5	7		dB
Folward Hansler Gaill	S21e   <sup>2</sup> 2	V <sub>CE</sub> =2V, I <sub>C</sub> =3mA, f=1GHz		10.5		dB
Noise Figure	NF	V <sub>CE</sub> =1V, I <sub>C</sub> =1mA, f=1GHz		2.6	4.5	dB



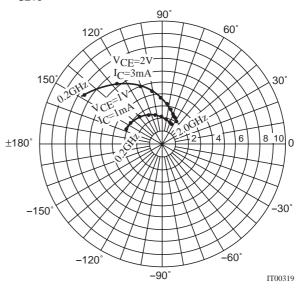


### S parameter

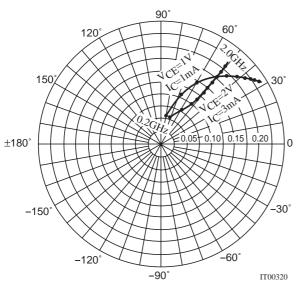
 $f{=}200\mbox{MHz}$  to  $2000\mbox{MHz}(200\mbox{MHz}\mbox{ Step})$  S11e



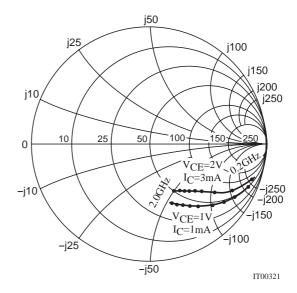
 $f{=}200\mbox{MHz}$  to  $2000\mbox{MHz}(200\mbox{MHz}$  Step) S21e



 $f{=}200\mbox{MHz}$  to  $2000\mbox{MHz}(200\mbox{MHz}\mbox{ Step})$  S12e



 $f{=}200MHz$  to  $2000MHz(200MHz\ Step)$  S22e



#### FH104

#### S Parameters (Common emitter)

 $V_{CE}=1V$ ,  $I_{C}=1mA$ ,  $Z_{O}=50\Omega$ 

Freq (MHz)	S <sub>11</sub>	∠S <sub>11</sub>	S <sub>21</sub>	∠S <sub>21</sub>	S <sub>12</sub>	∠S <sub>12</sub>	S <sub>22</sub>	∠S <sub>22</sub>
200	0.940	-17.9	3.228	159.6	0.058	77.1	0.972	-12.2
400	0.863	-33.7	2.983	143.7	0.107	66.6	0.914	-22.7
600	0.778	-48.0	2.732	129.9	0.145	58.1	0.844	-31.7
800	0.698	-60.5	2.469	117.7	0.173	50.9	0.773	-39.6
1000	0.608	-73.5	2.320	106.2	0.195	45.4	0.717	-46.0
1200	0.546	-84.7	2.106	96.3	0.210	40.9	0.668	-51.7
1400	0.470	-96.2	1.977	87.1	0.129	37.6	0.624	-56.5
1600	0.418	-106.4	1.826	78.8	0.224	35.3	0.590	-60.6
1800	0.388	-117.3	1.700	72.2	0.230	33.8	0.562	-64.3
2000	0.354	-127.0	1.615	65.9	0.234	32.9	0.546	-67.5

#### $V_{CE}=2V$ , $I_{C}=3mA$ , $Z_{O}=50\Omega$

Freq (MHz)	S <sub>11</sub>	∠S <sub>11</sub>	S <sub>21</sub>	∠S <sub>21</sub>	S <sub>12</sub>	∠S <sub>12</sub>	S <sub>22</sub>	∠S <sub>22</sub>
200	0.839	-30.6	7.428	149.3	0.050	71.4	0.916	-18.3
400	0.672	-53.7	6.016	128.5	0.083	60.6	0.778	-30.2
600	0.536	-71.7	4.908	113.6	0.105	55.1	0.672	-37.1
800	0.431	-85.7	4.073	101.9	0.121	52.5	0.597	-41.9
1000	0.360	-99.0	3.494	92.7	0.135	51.4	0.548	-45.7
1200	0.310	-111.4	3.033	84.4	0.150	50.9	0.514	-49.2
1400	0.265	-122.6	2.694	77.4	0.162	50.9	0.492	-52.3
1600	0.242	-134.7	2.422	70.9	0.175	51.0	0.475	-55.6
1800	0.228	-148.0	2.205	65.9	0.189	51.1	0.461	-59.0
2000	0.217	-157.2	2.061	60.8	0.205	51.0	0.456	-61.8

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